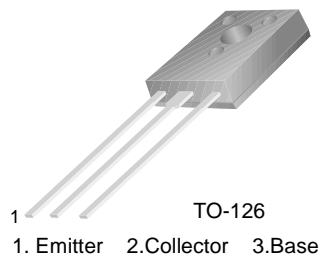


## KSB772

### Audio Frequency Power Amplifier

- Low Speed Switching
- Complement to KSD882



### PNP Epitaxial Silicon Transistor

#### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter  | Value      | Units            |
|-----------|--|------------|------------------|
| $V_{CBO}$ | Collector-Base Voltage                           | - 40       | V                |
| $V_{CEO}$ | Collector-Emitter Voltage                        | - 30       | V                |
| $V_{EBO}$ | Emitter-Base Voltage                             | - 5        | V                |
| $I_C$     | Collector Current (DC)                           | - 3        | A                |
| $I_{CP}$  | *Collector Current (Pulse)                       | - 7        | A                |
| $I_B$     | Base Current (DC)                                | - 0.6      | A                |
| $P_C$     | Collector Dissipation ( $T_C=25^\circ\text{C}$ ) | 10         | W                |
| $P_C$     | Collector Dissipation ( $T_a=25^\circ\text{C}$ ) | 1          | W                |
| $T_J$     | Junction Temperature                             | 150        | $^\circ\text{C}$ |
| $T_{STG}$ | Storage Temperature                              | - 55 ~ 150 | $^\circ\text{C}$ |

\*  $PW \leq 10\text{ms}$ , Duty Cycle  $\leq 50\%$

#### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol        | Parameter                              | Test Condition  | Min. | Typ.  | Max.  | Units         |
|---------------|--|---|------|-------|-------|---------------|
| $I_{CBO}$     | Collector Cut-off Current              | $V_{CB} = -30\text{V}$ , $I_E = 0$                      |      |       | - 1   | $\mu\text{A}$ |
| $I_{EBO}$     | Emitter Cut-off Current                | $V_{EB} = -3\text{V}$ , $I_C = 0$                       |      |       | - 1   | $\mu\text{A}$ |
| $h_{FE1}$     | * DC Current Gain                      | $V_{CE} = -2\text{V}$ , $I_C = -20\text{mA}$            | 30   | 220   |       |               |
| $h_{FE2}$     |  | $V_{CE} = -2\text{V}$ , $I_C = -1\text{A}$              | 60   | 160   | 400   |               |
| $V_{CE(sat)}$ | * Collector-Emitter Saturation Voltage | $I_C = -2\text{A}$ , $I_B = -0.2\text{A}$               |      | - 0.3 | - 0.5 | V             |
| $V_{BE(sat)}$ | * Base-Emitter Saturation Voltage      | $I_C = -2\text{A}$ , $I_B = -0.2\text{A}$               |      | - 1.0 | - 2.0 | V             |
| $f_T$         | Current Gain Bandwidth Product         | $V_{CE} = -5\text{V}$ , $I_E = -0.1\text{A}$            |      | 80    |       | MHz           |
| $C_{ob}$      | Output Capacitance                     | $V_{CB} = -10\text{V}$ , $I_E = 0$<br>$f = 1\text{MHz}$ |      | 55    |       | pF            |

\* Pulse Test:  $PW \leq 350\mu\text{s}$ , Duty Cycle  $\leq 2\%$

#### $h_{FE}$ Classification

| Classification | R        | O         | Y         | G         |
|----------------|----------|-----------|-----------|-----------|
| $h_{FE2}$      | 60 ~ 120 | 100 ~ 200 | 160 ~ 320 | 200 ~ 400 |

# Typical Characteristics

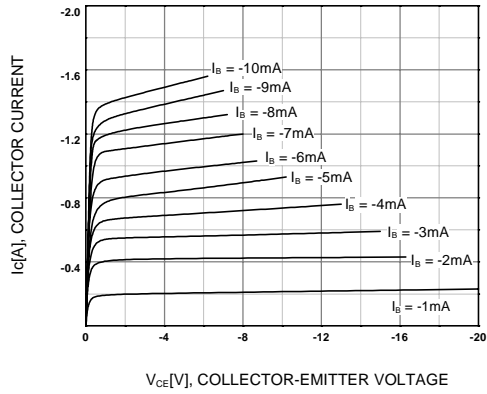


Figure 1. Static Characteristic

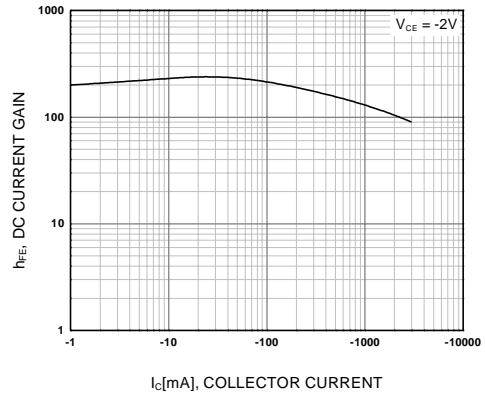


Figure 2. DC current Gain

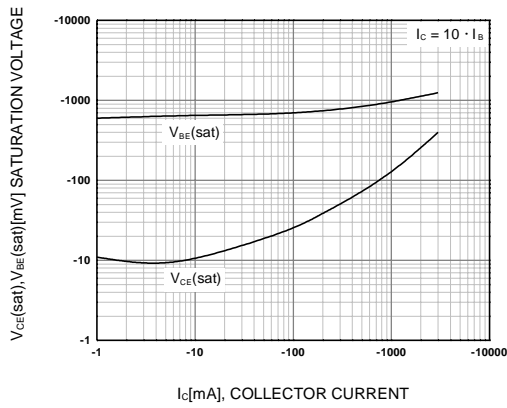


Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage

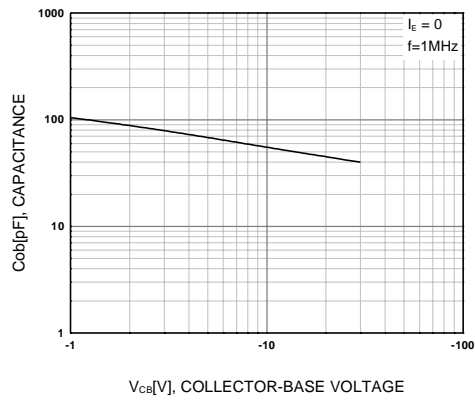


Figure 4. Collector Output Capacitance

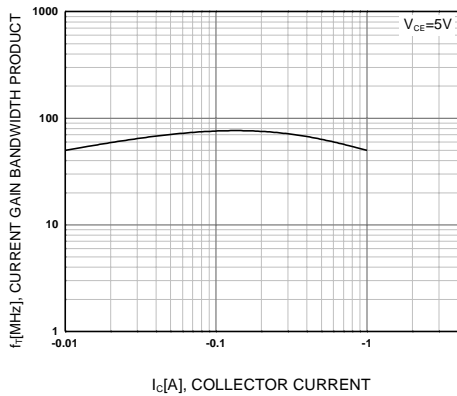


Figure 5. Current Gain Bandwidth Product

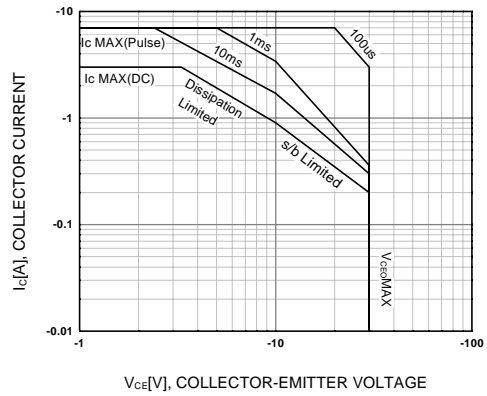


Figure 6. Safe Operating Area

# Typical Characteristics (Continued)

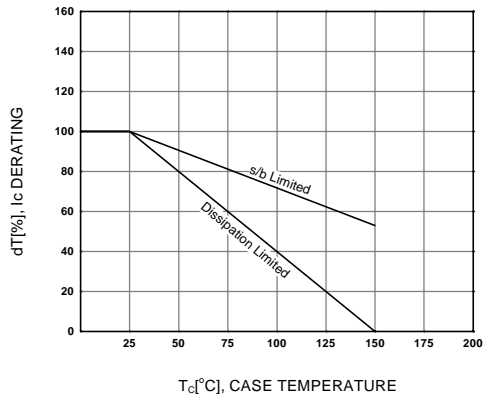


Figure 7. Derating Curve of Safe Operating Areas

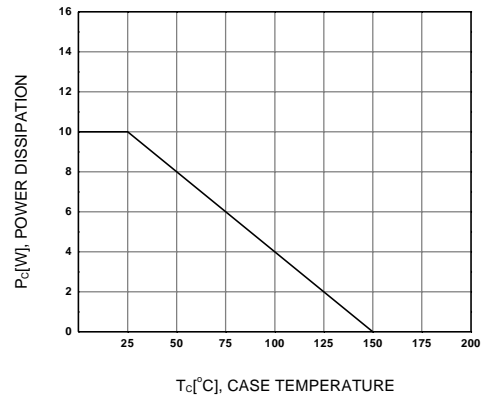


Figure 8. Power Derating

# Package Dimensions

KSB772

## TO-126



Dimensions in Millimeters

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|----------------------|---------------|-------------|
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| Bottomless™          | ISOPLANAR™    | SyncFET™    |
| CoolFET™             | MICROWIRE™    | TinyLogic™  |
| CROSSVOLT™           | POP™          | UHC™        |
| E <sup>2</sup> CMOS™ | PowerTrench®  | VCX™        |
| FACT™                | QFET™         |             |
| FACT Quiet Series™   | QS™           |             |
| FAST®                | Quiet Series™ |             |
| FASTr™               | SuperSOT™-3   |             |
| GTO™                 | SuperSOT™-6   |             |

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